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|  | <h2>SI7852ADP-T1-E3</h2> |
| | <p>Hersteller-Teilenummer: SI7852ADP-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 80V 30A PPAK SO-8</p> <p>Datenblätter:  SI7852ADP-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 3010 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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|---|---|
| Teilenummer | SI7852ADP-T1-E3 |
| Hersteller | Vishay / Siliconix |
| Beschreibung | MOSFET N-CH 80V 30A PPAK SO-8 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs , |
| Teilstatus | 3010 pcs Stock |
| Serie | TrenchFET® |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | PowerPAK® SO-8 |
| Supplier Device-Gehäuse | PowerPAK® SO-8 |
| Verlustleistung (max) | 5W (Ta), 62.5W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 80V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 30A (Tc) |
| Rds On (Max) @ Id, Vgs | 17 mOhm @ 10A, 10V |
| VGS (th) (Max) @ Id | 4.5V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 45nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 1825pF @ 40V |
| Antriebsspannung (Max Rds On, Min Rds On) | 8V, 10V |
| Vgs (Max) | ±20V |
| Verpackung | Tape & Reel (TR) |

SI7852ADP-T1-E3 ist neu im Original, Suche SI7852ADP-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7852ADP-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7852ADP-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

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|  <p>SI7852ADP-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 80V 30A PPAK SO-8</p> |  <p>SI7852ADP-T1-GE3 Vishay / Siliconix MOSFET N-CH 80V 30A PPAK SO-8</p> |  <p>SI7852DP VISHAY SI7852DP VISHAY</p> |  <p>SI7852DP-T1 VISHAY SI7852DP-T1 VISHAY</p> |
|  <p>SI7850DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 60V 6.2A PPAK SO-8</p> |  <p>SI7850DP-T1-E3. VIS VIS QFN8</p> |  <p>SI7852ADP SI SI7852ADP SI</p> |  <p>SI7850DP-T1-E3 Vishay / Siliconix MOSFET N-CH 60V 6.2A PPAK SO-8</p> |

heiße Teile

Mehr

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| SI7844DP-T1-E3 | SI7844DP-T1-GE3 | SI7844DP-T1-GE3 | SI7846DP | SI7846DP-T1-E3 |
| SI7846DP-T1-E3 | SI7846DP-T1-GE3 | SI7846DP-T1-GE3 | SI7846DP-TI | SI7846SAC |
| SI7848BDP-T1-E3 | SI7848BDP-T1-E3 | SI7848BDP-T1-GE3 | SI7848BDP-T1-GE3 | SI7848DP |
| SI7848DP-T1-E3 | SI7848DP-T1-E3 | SI7848DP-T1-GE3 | SI7850DP | SI7850DP-T1-E3 |
| SI7850DP-T1-E3 | SI7850DP-T1-GE3 | SI7850DP-T1-GE3 | SI7852ADP | SI7852ADP-T1-E3 |
| SI7852ADP-T1-GE3 | SI7852ADP-T1-GE3 | SI7852DP | SI7852DP-T1-E3 | SI7852DP-T1-E3 |
| SI7852DP-T1-GE3 | SI7852DP-T1-GE3 | SI7856ADP | SI7856ADP-T1-E3 | SI7856ADP-T1-E3 |
| SI7856ADP-T1-GE3 | SI7856ADP-T1-GE3 | SI7856DP-T1 | SI7856DP-T1-GE3 | SI7856DP-TI-E3 |
| SI7858ADP | SI7858ADP-T1-E3 | SI7858ADP-T1-E3 | SI7858ADP-T1-GE3 | SI7858ADP-T1-GE3 |
| SI7858BDP | SI7858BDP-T1-E3 | SI7860ADP | SI7860ADP-T1-E3 | SI7860ADP-T1-E3 |

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